DISCRETE SEMICONDUCTORS

DATA SHEET

PDTC123E series NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

Product data sheet Supersedes data of 2004 Mar 18 2004 Aug 06



NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V_{CEO}	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	2.2	_	kΩ
R2	bias resistor	2.2	_	kΩ

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PAC	KAGE	MARKING CORE	PNP COMPLEMENT	
TYPE NUMBER	PHILIPS	EIAJ	MARKING CODE		
PDTC123EE	SOT416	SC-75	5A	PDTA123EE	
PDTC123EEF	SOT490	SC-89	6A	PDTA123EEF	
PDTC123EK	SOT346	SC-59	48	PDTA123EK	
PDTC123EM	SOT883	SC-101	G1	PDTA123EM	
PDTC123ES	SOT54 (TO-92)	SC-43	TC123E	PDTA123ES	
PDTC123ET	SOT23	_	*26 ⁽¹⁾	PDTA123ET	
PDTC123EU	SOT323	SC-70	*48 ⁽¹⁾	PDTA123EU	

Note

^{1. * =} p: Made in Hong Kong.

^{* =} t: Made in Malaysia.

^{* =} W: Made in China.

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL		PINNING
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION
PDTC123ES		1	base
		2	collector
	R1 R2 3	3	emitter
PDTC123EE PDTC123EEF PDTC123EK PDTC123ET PDTC123EU	Top view Top view Top view Top view	1 2 3	base emitter collector
PDTC123EM	2 R1 R2 Dottom view	1 2 3	base emitter collector
	MHC506		

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

ORDERING INFORMATION

TYPE NUMBER		PACKAGE						
ITPE NUMBER	NAME	DESCRIPTION	VERSION					
PDTC123EE	_	plastic surface mounted package; 3 leads	SOT416					
PDTC123EEF	_	plastic surface mounted package; 3 leads	SOT490					
PDTC123EK	_	plastic surface mounted package; 3 leads	SOT346					
PDTC123EM	-	leadless ultra small package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883					
PDTC123ES	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54					
PDTC123ET	_	plastic surface mounted package; 3 leads	SOT23					
PDTC123EU	_	plastic surface mounted package; 3 leads	SOT323					

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	50	V
V _{CEO}	collector-emitter voltage	open base	_	50	V
V _{EBO}	emitter-base voltage	open collector	_	10	V
VI	input voltage				
	positive		_	+12	V
	negative		_	-10	V
Io	output current (DC)		_	100	mA
I _{CM}	peak collector current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT416	note 1	_	150	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	_	_	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	_	_	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	_	_	2	mA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 20 \text{ mA}$	30	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	_	150	mV
$V_{i(off)}$	input-off voltage	I _C = 1 mA; V _{CE} = 5 V	_	1.2	0.5	V
$V_{i(on)}$	input-on voltage	$I_C = 20 \text{ mA}; V_{CE} = 0.3 \text{ V}$	2	1.6	_	V
R1	input resistor		1.54	2.2	2.86	kΩ
<u>R2</u> R1	resistor ratio		0.8	1	1.2	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	_	_	2.5	pF

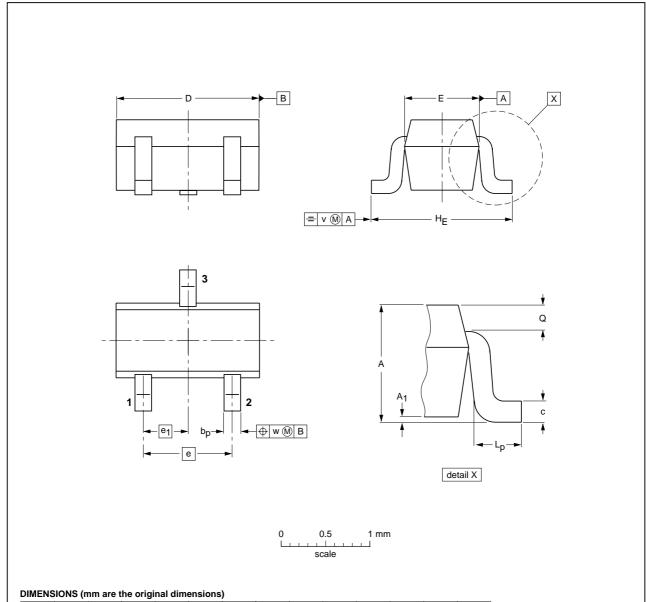
NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

PACKAGE OUTLINES

Plastic surface-mounted package; 3 leads

SOT416



UNIT	Α	A ₁ max	bp	С	D	E	е	e ₁	HE	Lp	ø	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

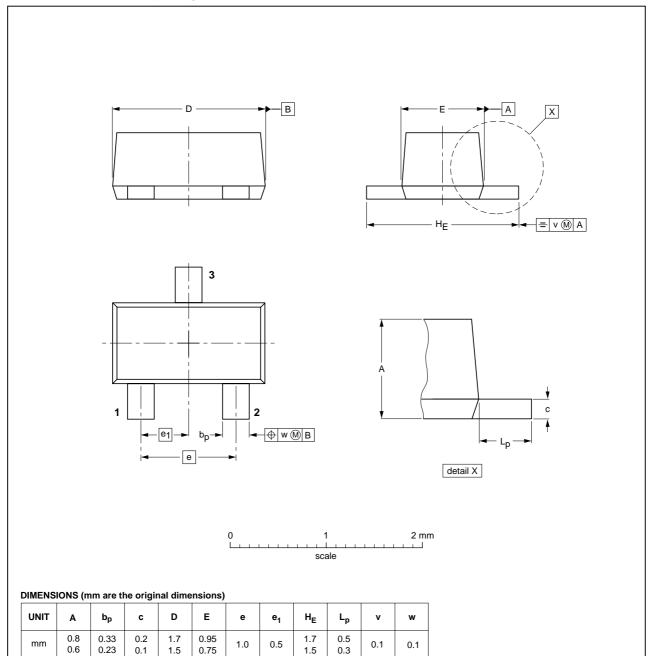
OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEDEC JEITA		PROJECTION	ISSUE DATE
SOT416			SC-75			04-11-04 06-03-16

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

Plastic surface-mounted package; 3 leads

SOT490



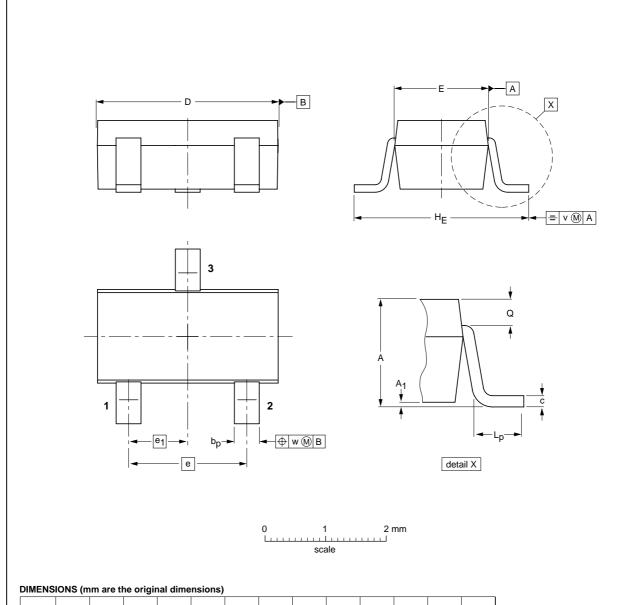
VERSION IEC JEDEC JEITA PROJECTION 95-97	OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE	
	VERSION	IEC	JEDEC	DEC JEITA		PROJECTION	ISSUE DATE	
30-09 06-03	SOT490			SC-89			05-07-28 06-03-16	

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

Plastic surface-mounted package; 3 leads

SOT346



UNIT	Α	A ₁	bp	С	D	E	е	e ₁	HE	Lp	Q	v	w
mm	1.3 1.0	0.1 0.013	0.50 0.35	0.26 0.10	3.1 2.7	1.7 1.3	1.9	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2

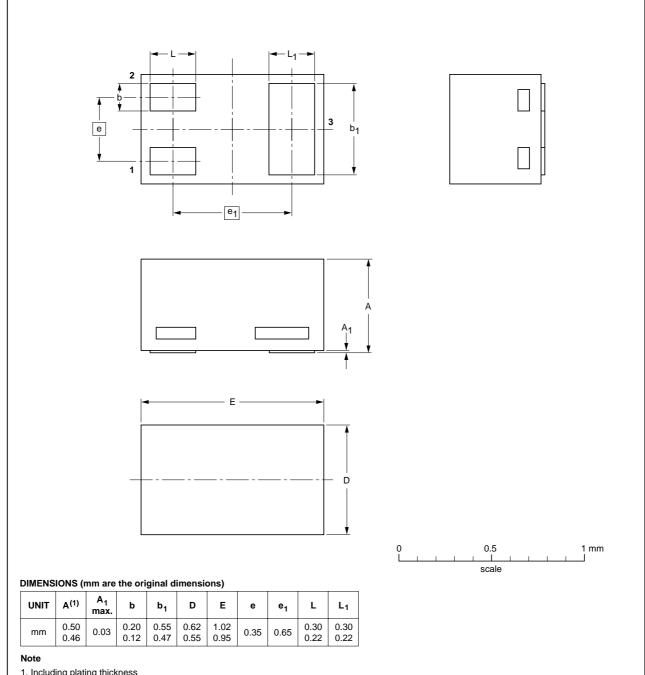
OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59A			04-11-11 06-03-16	

NPN resistor-equipped transistors; $R1 = 2.2 \text{ k}\Omega$, $R2 = 2.2 \text{ k}\Omega$

PDTC123E series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



1. Including plating thickness

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT883			SC-101			03-02-05 03-04-03

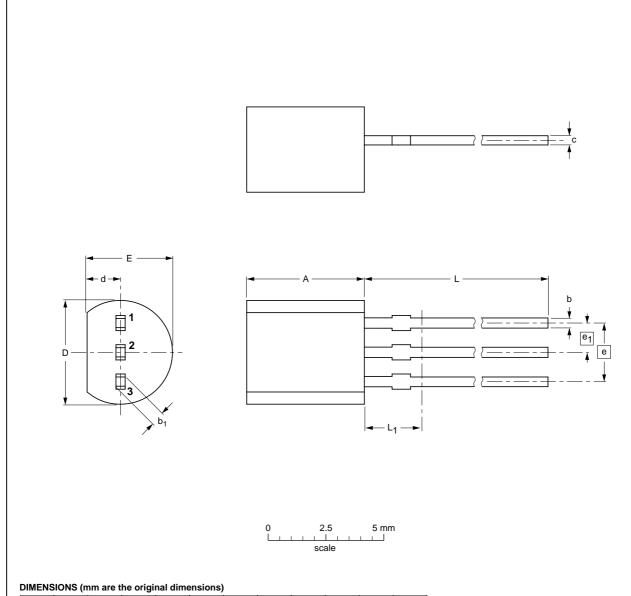
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NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	Α	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.	
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

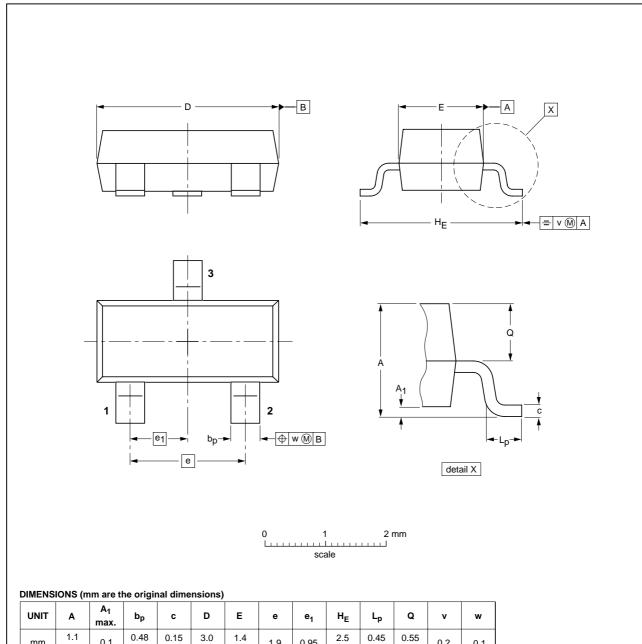
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			-04-06-28- 04-11-16

NPN resistor-equipped transistors; $R1 = 2.2 \text{ k}\Omega$, $R2 = 2.2 \text{ k}\Omega$

PDTC123E series

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE		REFER	EUROPEAN	ICCUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB				-04-11-04 06-03-16

0.2

0.1

1.9

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0.38

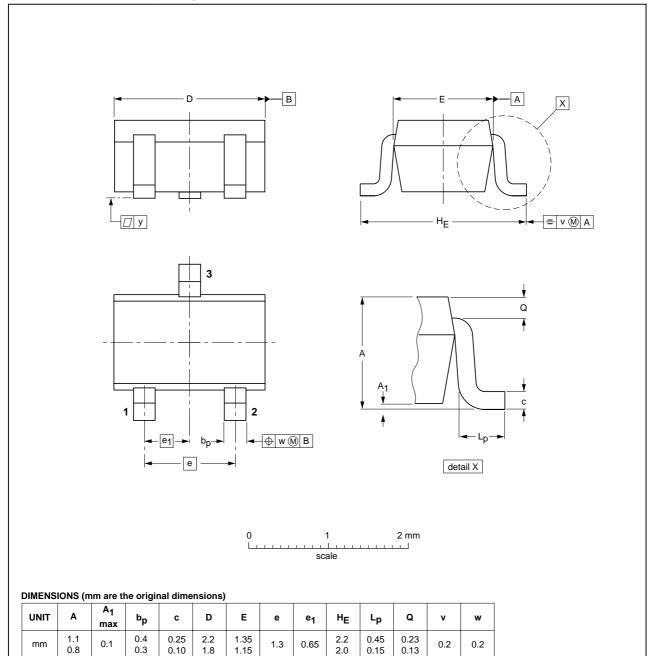
0.9

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

Plastic surface-mounted package; 3 leads

SOT323



OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT323			SC-70			-04-11-04- 06-03-16
					— •	00-03-10

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 2.2 k Ω

PDTC123E series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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Customer notification

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Contact information

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